TIP145T/146T/147T

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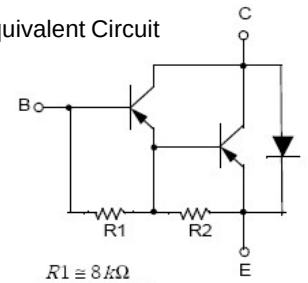
TIP145T/146T/147T

Monolithic Construction With Built In Base-Emitter Shunt Resistors

- High DC Current Gain : hFE=1000 @ VCE= -4V, IC= -3A (Min.)
- Collector-Emitter Sustaining Voltage
- Low Collector-Emitter Saturation Voltage
- Industrial Use
- Complementary to TIP140/141/142

PNP Epitaxial Silicon Darlington Transistor

Equivalent Circuit



$R1 \cong 8k\Omega$
$R2 \cong 0.12k\Omega$

TO-220
1. Base
2. Collector
3. Emitter

Absolute Maximum Ratings T_a=25℃ unless otherwise noted

CHARACTERISTICS	SYMBOL	RATING	UNIT
Collector-Base Voltage : TIP145T	V_{CBO}	-60	V
: TIP146T		-80	V
: TIP147T		-100	V
Collector-Emitter Voltage : TIP145T	V_{CEO}	-60	V
: TIP146T		-80	V
: TIP147T		-100	V
Emitter-Base Voltage	V_{EBO}	-5	V
Collector Current(DC)	I_C	-10	A
Collector Current(Pulse)	I_{CP}	-15	A
Base Current	I_B	-0.5	A
Collector Dissipation(Ta=25℃)	P_C	2	W
Collector Dissipation(Tc=25℃)	P_C	80	W
Junction Temperature	T_J	150	℃
Storage Temperature	T_{STG}	-65~150	℃

Electrical Characteristics T_a=25℃ unless otherwise noted

CHARACTERISTICS	SYMBOL	Test Condition	Min	Max	Unit
Collector-Emitter Sustaining Voltage	V_{CEO}(SUS)				
: TIP145T		I_C=-30mA, I_B=0	-60		V
: TIP146T			-80		V
: TIP147T			-100		V
Collector Cut-off Current	I_{CEO}				
: TIP145T		V_{CE}=-30V,I_B=0		-2	mA
: TIP146T		V_{CE}=-40V,I_B=0		-2	mA
: TIP147T		V_{CE}=-50V,I_B=0		-2	mA
Collector Cut-off Current	I_{CBO}				
: TIP145T		V_{CE}=-60V,I_E=0		-1	mA
: TIP146T		V_{CE}=-80V,I_E=0		-1	mA
: TIP147T		V_{CE}=-100V,I_E=0		-1	mA
Emitter Cut-off Current	I_{EBO}	V_{EB}=-5V,I_C=0		-2	mA
DC Current Gain	h_{FE}	V_{CE}=-4V,I_C=-5A	1000		
		V_{CE}=-4V,I_C=-10A	500		
Collector-Emitter Saturation Voltage	V_{CE}(sat)	I_C=-5A,I_B=-10mA		-2	V
		I_C=-10A,I_B=-40mA		-3	V
Base-Emitter ON Voltage	V_{BE}(on)	V_{CE}=-4V,I_C=-10A		-3	V
Output Capacitance	C_{ob}	V_{CB}=10V,I_E=0, f=0.1MHz		200	pF

* Pulse Test: PW≤300us, Duty Cycle≤2%

Typical Characteristics

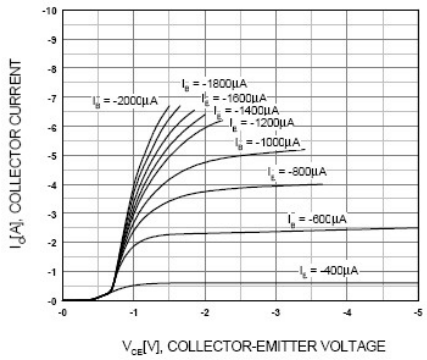


Figure 1. Static Characteristic

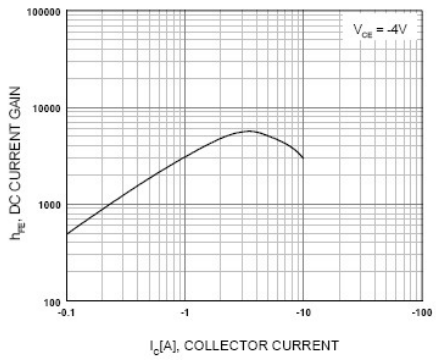


Figure 2. DC current Gain

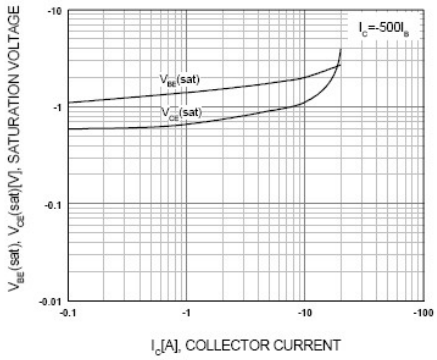


Figure 3. Collector-Emitter Saturation Voltage
Base-Emitter Saturation Voltage

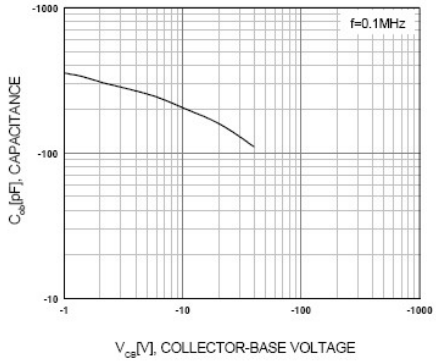


Figure 4. Collector Output Capacitance

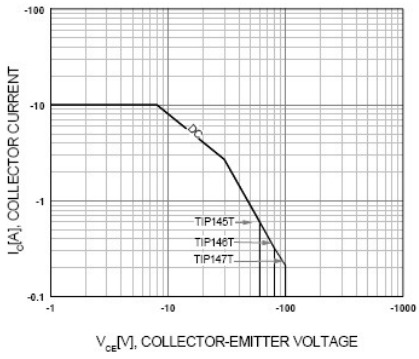


Figure 5. Safe Operating Area

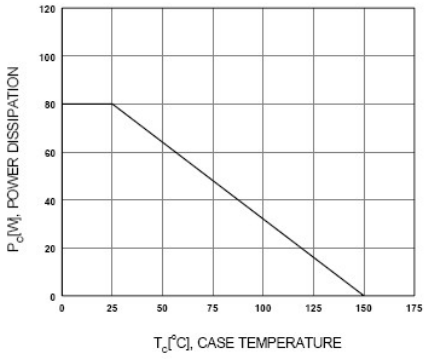
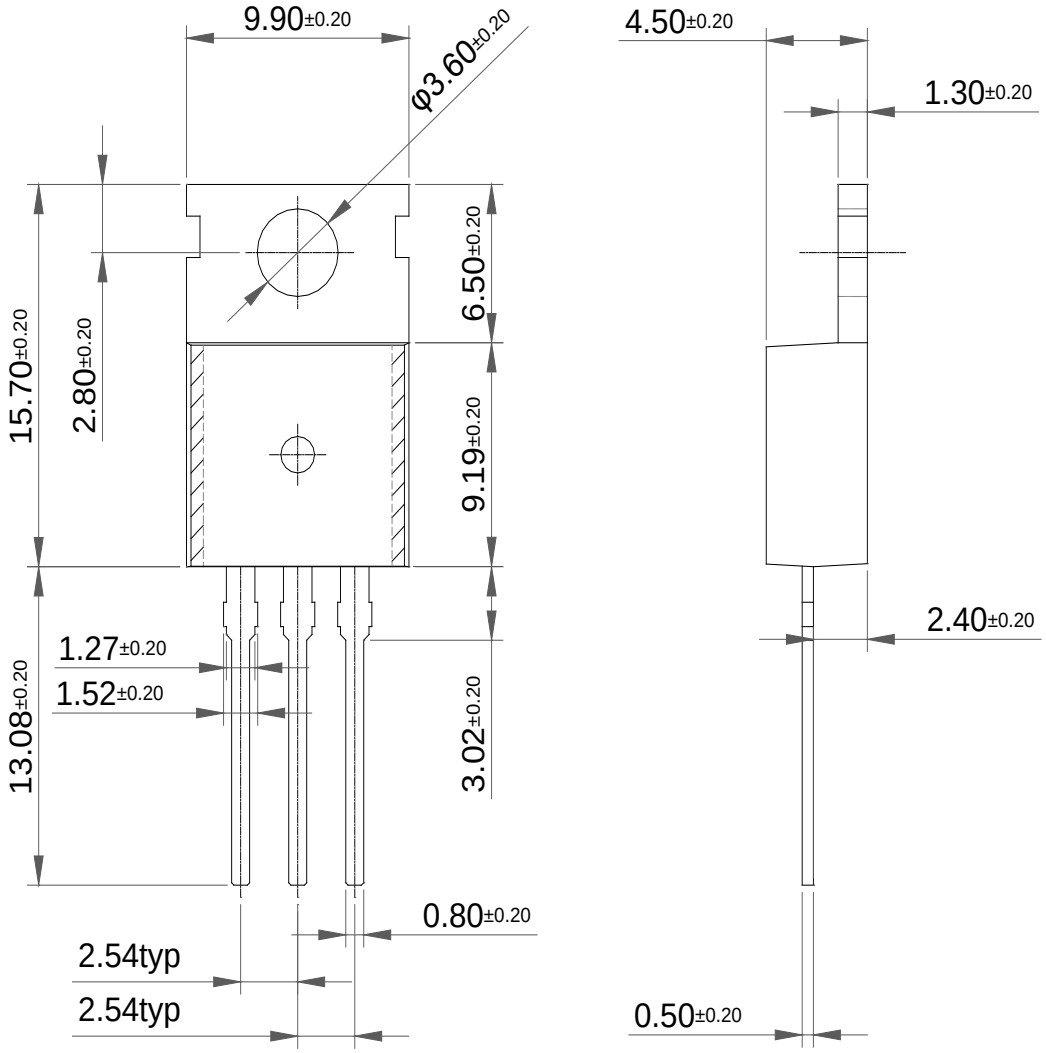


Figure 6. Power Derating

Package Dimension

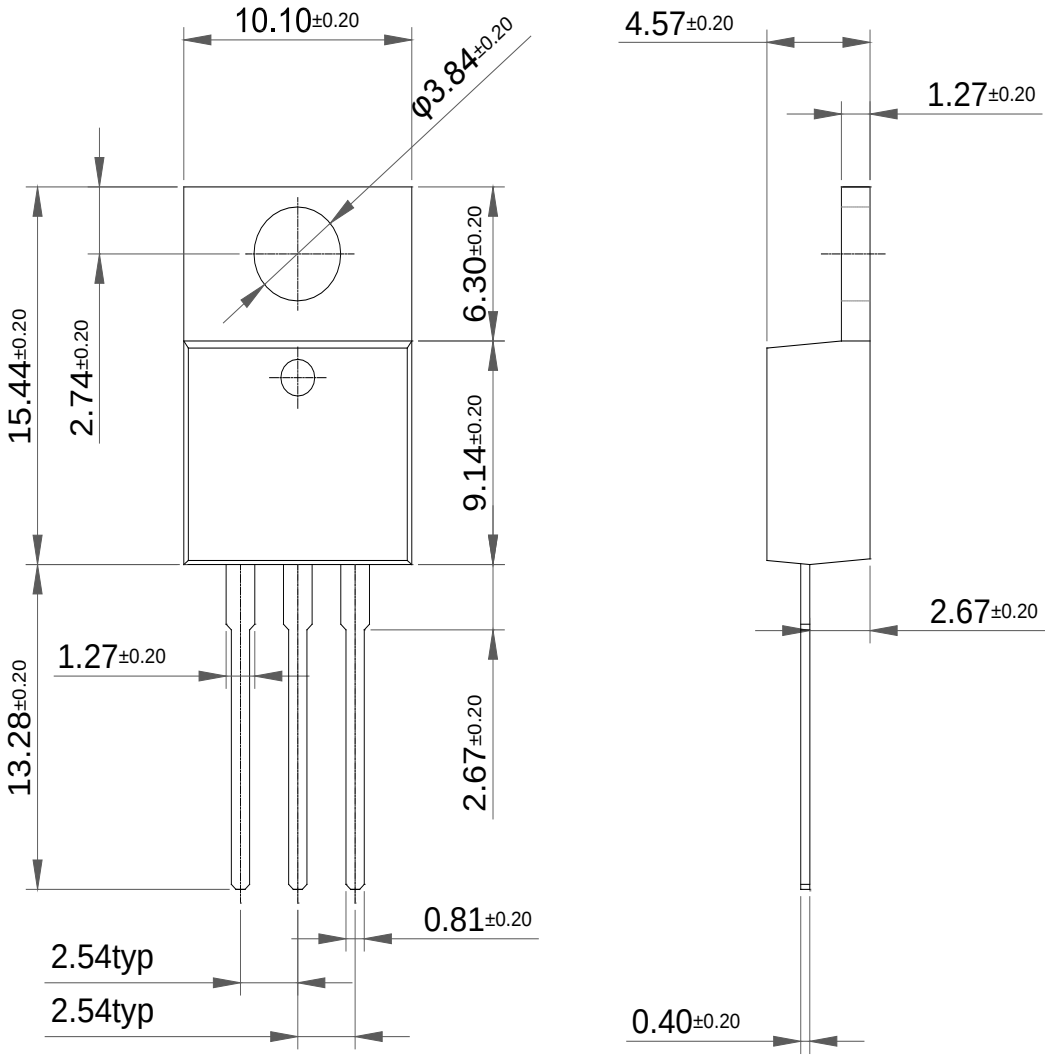
TO-220 (A)



Dimensions in Millimeters

Package Dimension

TO-220 (B)



Dimensions in Millimeters